

TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT
(Under 37 CFR 1.97(b) or 1.97(c))

In Re Application: **Fwu-Iuan Hshieh et al.**

Serial No. Unassigned	Filing Date Filed Herewith	Examiner Unassigned	Group A Unassigned
--------------------------	-------------------------------	------------------------	-----------------------

**TRENCH MOSFET DEVICE WITH POLYCRYSTALLINE SILICON SOURCE CONTACT
STRUCTURE**

Payment of Fee

(Only complete if Applicant elects to pay the fee set forth in 37 CFR 1.17(p))

- ☐ A check in the amount of _____ is attached.
- ☐ The Assistant Commissioner is hereby authorized to charge and credit Deposit Account No. _____ as described below. A duplicate copy of this sheet is enclosed.
- ☐ Charge the amount of _____
- ☐ Credit any overpayment.
- ☐ Charge any additional fee required.

Certificate of Transmission by Facsimile*

I certify that this document and authorization to charge deposit account is being facsimile transmitted to the United States Patent and Trademark Office (F

(Date)

Signature

Typed or Printed Name of Person Signing Certificate

Certificate of Mailing by ^{Express} First Class Mail

I certify that this document and fee is being deposited
11/20/01 with the U.S. Postal Service
as first class mail under 37 C.F.R. 1.8 and is
addressed to the Assistant Commissioner for Patents,
Washington, D.C. 20231.

Marjorie Scariati
Signature of Person Mailing Correspondence

Marjorie Scariati

Typed or Printed Name of Person Mailing Certificate

*This certificate may only be used if paying by deposit account.

Karin L. Williams
Signature

Dated: 11/20/01

Karin L. Williams Reg. No. 36,721
Mayer Fortkort & Williams, PC
251 North Avenue West, 2nd Floor
Westfield, NJ 07090

Tel.: 908-518-7700
Fax: 908-518-7795

cc:

TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT
(Under 37 CFR 1.97(b) or 1.97(c))

Docket No.
GS 150

In Re Application Of: **Fwu-Iuan Hshieh et al.**

Serial No.
Unassigned

Filing Date
Filed Herewith

Examiner
Unassigned

Group Art Unit
Unassigned

Title: **TRENCH MOSFET DEVICE WITH POLYCRYSTALLINE SILICON SOURCE CONTACT
STRUCTURE**

Address to:
**Assistant Commissioner for Patents
Washington, D.C. 20231**

37 CFR 1.97(b)

- ☒ The Information Disclosure Statement submitted herewith is being filed within three months of the filing of a national application other than a continued prosecution application under 37 CFR 1.53(d); within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; before the mailing of a first Office Action on the merits, or before the mailing of a first Office Action after the filing of a request for continued examination under 37 CFR 1.114.

37 CFR 1.97(c)

- ☐ The Information Disclosure Statement submitted herewith is being filed after the period specified in 37 CFR 1.97(b), provided that the Information Disclosure Statement is filed before the mailing date of a Final Action under 37 CFR 1.113, a Notice of Allowance under 37 CFR 1.311, or an Action that otherwise closes prosecution in the application, and is accompanied by one of:
- ☐ the statement specified in 37 CFR 1.97(e);
- OR**
- ☐ the fee set forth in 37 CFR 1.17(p).